

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent No. : 7,423,245
Issue Date : September 9, 2008
Applicants : Arend et al.
Title : HIGH RESPONSIVITY HIGH BANDWIDTH METAL-SEMICONDUCTOR-
METAL OPTOELECTRONIC DEVICE

TC/A.U. : 2878
Examiner : Francis M. Legasse

Confirmation No. : 5438
Docket No. : 1038-12 PCT/US
Dated : March 20, 2009

Certificate of EFS-Web Transmission

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PO Box 1450
Alexandria, Virginia 22313-1450

I hereby certify that this correspondence is being transmitted
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Joyce Peterson
(Printed Name)

/joyce peterson/
(Signature)

**REQUEST FOR CERTIFICATE OF CORRECTION OF
PATENT PURSUANT TO 37 C.F.R. §1.322 and §1.323**

Sir:

Please issue a Certificate of Correction in accordance with 37 C.F.R. §1.322 and §1.323
to correct the errors in the patent as set forth hereinbelow and on the enclosed copy of Patent
Office Form PTO-1050.

IN THE PATENT:

Column 8, line 47:

Now reads: "1000 m"

Should read: -- 1000 nm --

Column 13, line 16

Now reads: "electrodes 12"

Should read: -- electrodes 112 --

Column 17, line 26

Now reads: "surface plasmon in prior art"

Should read: -- surface plasmon resonance in prior art --

Column 22, line 53

Now reads: "dielectrics were Me same"

Should read: -- dielectrics were the same --

Applicants submit that the errors marked above occurred through no fault of the Applicants. Accordingly, no fee is due. If any additional fees are due or an overpayment has been made, please charge our Deposit Account No. 08-2461 or credit our Deposit Account for such sum.

Respectfully submitted,

/rod s. turner/

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UNITED STATES PATENT AND TRADEMARK OFFICE

CERTIFICATE OF CORRECTION

PATENT NO. : US 7,423,245 B2
ISSUE DATE : September 9, 2008
INVENTOR(S) : Arend et al.

It is certified that errors appear in the above-identified patent and that said Letters Patent are hereby corrected as shown below:

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PATENT NO. US 7,423,254 B2